Lead-free Green

## Features

- Epitaxial Planar Die Construction
- Selectively Paired NPN Transistors \& Zener Diodes for Series Pass Voltage Regulator Circuits
- Ideally Suited for Automated Assembly Processes
- Lead, Halogen and Antimony Free, RoHS Compliant (Note 1)
- "Green" Device (Note 2)


## Mechanical Data

- Case: SOT363
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish annealed over Alloy 42 leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Weight: 0.006 grams (approximate)


Top View


Top View Pin Configuration

## Ordering Information (Note 3)

| Device | Packaging | Shipping |
| :---: | :---: | :---: |
| DVR5V0W-7 | SOT363 | 3000/Tape \& Reel |

Notes: 1. No purposefully added lead.
2. Diodes Inc's "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
3. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

## Marking Information



VR04 = Product Type Marking Code
YM = Date Code Marking
Y = Year ex: Y = 2011
$M=$ Month ex: 9 = September

| Year | 2004 | 2005 | 2006 | 2007 | 2008 | 2009 | 2010 | 2011 | 2012 | 2013 | 2014 | 2015 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Code | R | S | T | U | V | W | X | Y | Z | A | B | C |
| Month | Jan | Feb | Mar | Apr | May | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
| Code | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | O | N | D |

Maximum Ratings, Total Device
$@ T_{A}=25^{\circ} \mathrm{C}$ unless otherwise specified

| Characteristic |  | Symbol | Value | Unit |
| :---: | :---: | :---: | :---: | :---: |
| Power Dissipation | (Note 4) | $\mathrm{P}_{\mathrm{d}}$ | 200 | mW |
| Thermal Resistance, Junction to Ambient | (Note 4) | $\mathrm{R}_{\text {өJA }}$ | 625 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Operating and Storage Temperature Range |  | $\mathrm{T}_{\mathrm{j},} \mathrm{T}_{\text {STG }}$ | -55 to +150 | ${ }^{\circ} \mathrm{C}$ |

## Maximum Ratings, NPN Transistor $@ \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise specified

| Characteristic | Symbol | Value | Unit |
| :--- | :---: | :---: | :---: |
| Collector-Base Voltage | $\mathrm{V}_{\text {CBO }}$ | 45 | V |
| Collector-Emitter Voltage | $\mathrm{V}_{\text {CEO }}$ | 18 | V |
| Emitter-Base Voltage | $\mathrm{V}_{\text {EBO }}$ | 5 | V |
| Collector Current - Continuous | $\mathrm{IC}_{C}$ | 1 | A |

## Maximum Ratings, Zener Element $@ T_{A}=25^{\circ} \mathrm{C}$ unless otherwise specified

| Characteristic | Symbol | Value | Unit |
| :---: | :---: | :---: | :---: |
| Forward Voltage $\quad @ \mathrm{I}_{\mathrm{F}}=10 \mathrm{~mA}$ | $\mathrm{~V}_{\mathrm{F}}$ | 0.9 | V |

## Electrical Characteristics, NPN Transistor $\quad \mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise specified

| Characteristic | Symbol | Min | Max | Unit | Test Condition |
| :---: | :---: | :---: | :---: | :---: | :---: |
| OFF CHARACTERISTICS (Note 5) |  |  |  |  |  |
| Collector-Base Breakdown Voltage | $\mathrm{V}_{\text {(BR) }}$ CBO | 45 | - | V | $\mathrm{I}_{\mathrm{C}}=100 \mu \mathrm{~A}, \mathrm{I}_{\mathrm{E}}=0$ |
| Collector-Emitter Breakdown Voltage | $\mathrm{V}_{\text {(BR)CEO }}$ | 18 | - | V | $\mathrm{IC}_{\mathrm{C}}=1 \mathrm{~mA}, \mathrm{I}_{\mathrm{B}}=0$ |
| Emitter-Base Breakdown Voltage | $\mathrm{V}_{\text {(BR) }{ }^{\text {ebo }}}$ | 5 | - | V | $\mathrm{I}_{\mathrm{E}}=100 \mu \mathrm{~A}, \mathrm{I}_{\mathrm{C}}=0$ |
| Collector Cutoff Current | Icbo | - | 1 | $\mu \mathrm{A}$ | $\mathrm{V}_{C B}=40 \mathrm{~V}, \mathrm{IE}_{\mathrm{E}}=0$ |
| Emitter Cutoff Current | $\mathrm{l}_{\text {EBO }}$ | - | 1 | $\mu \mathrm{A}$ | $\mathrm{V}_{\mathrm{EB}}=4 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=0$ |
| ON CHARACTERISTICS (Note 5) |  |  |  |  |  |
| DC Current Gain | $\mathrm{h}_{\text {FE }}$ | 150 | 800 | - | $\mathrm{IC}=100 \mathrm{~mA}, \mathrm{~V}_{\text {CE }}=1 \mathrm{~V}$ |
| Collector-Emitter Saturation Voltage | $\mathrm{V}_{\text {CE(SAT) }}$ | - | 0.5 | V | $\mathrm{IC}_{\mathrm{C}}=300 \mathrm{~mA}, \mathrm{I}_{\mathrm{B}}=30 \mathrm{~mA}$ |
| SMALL SIGNAL CHARACTERISTICS |  |  |  |  |  |
| Output Capacitance | $\mathrm{C}_{\text {obo }}$ | - | 8 | pF | $\mathrm{V}_{\mathrm{CB}}=10 \mathrm{~V}, \mathrm{f}=1.0 \mathrm{MHz}, \mathrm{I}_{\mathrm{E}}=0$ |
| Current Gain-Bandwidth Product | $\mathrm{f}_{T}$ | 100 | - | MHz | $\mathrm{V}_{\mathrm{CB}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{E}}=50 \mathrm{~mA}, \mathrm{f}=100 \mathrm{MHz}$ |

Electrical Characteristics, Zener Element $@ T_{A}=25^{\circ} \mathrm{C}$ unless otherwise specified

| Zener Voltage Range (Note 6) |  |  |  | Maximum Reverse Leakage Current (Note 5) |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{z}}$ @ $\mathrm{IzT}^{\text {d }}$ |  |  | Izt |  |  |
| Nom (V) | Min (V) | Max (V) | mA | $\mu \mathrm{A}$ | V |
| 5.1 | 4.85 | 5.36 | 0.05 | 5 | 3 |

Notes: 4. Part mounted on FR-4 board with recommended pad layout, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
5. Short duration pulse test used to minimize self-heating effect.
6. Nominal Zener voltage is measured with the device junction in thermal equilibrium at $T_{T}=30^{\circ} \mathrm{C} \pm 1^{\circ} \mathrm{C}$.


Sample Applications


Sample Application for DVR5VOW:
$\mathrm{V}_{\mathrm{cc}}=6.0 \mathrm{~V} \quad \mathrm{R} 1=560 \Omega$
$\mathrm{Vo}(\mathrm{nom})=5.0 \mathrm{~V} \quad \mathrm{I}_{0}=100 \mathrm{~mA}$
Iq(typical) $=0.5 \mathrm{~mA} @ \mathrm{I}_{0}=0 \mathrm{~mA}$
Typical Vreg(load) $=0.2 \mathrm{~V}$ from $\mathrm{lo}=100 \mathrm{~mA}$ to 0 mA

Notes: 7. Resistor R1 not included.
8. Typical performance shown is under setup and operating conditions specified in the sample applications.
9. Recommended $\mathrm{V}_{\mathrm{cc}}(\mathrm{min}) \sim \mathrm{Vo}(\mathrm{nom})+1 \mathrm{~V}$.

## Package Outline Dimensions



## Suggested Pad Layout



| Dimensions | Value (in $\mathbf{~ m m}$ ) |
| :---: | :---: |
| $\mathbf{Z}$ | 2.5 |
| $\mathbf{G}$ | 1.3 |
| $\mathbf{X}$ | 0.42 |
| $\mathbf{Y}$ | 0.6 |
| $\mathbf{C 1}$ | 1.9 |
| $\mathbf{C 2}$ | 0.65 |

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